NSN 5962-01-133-1276

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View Online at https://aerobasegroup.com/nsn/5962-01-133-1276

Body Length:
0.840 inches
Body Width:
0.295 inches
Body Height:
0.180 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
An/apy-1 08783
Features Provided:
Hermetically sealed and low power and high speed and high performance
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.0 volts power source
Time Rating Per Chacteristic:
200.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Ram
Memory Capacity:
Unknown
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

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